Specification

Drawing No.	TKY1W-H1-14042-00
Issued Date.	Dec.2014,15

To: Digi-Key

Note : In case of specification change, KYOCERA Part Number also will be changed.

Product Name	SAW Oscillator
Product Model	KC7050T Series
Frequency	212.500MHz
Customer Part Number	_
Customer Specification Number	
KYOCERA Part Number	KC7050T212.500L3AEYF
Remarks: Pb-Free,RoHS Compliant., N	ISL=1

Customer Acceptance

Accept Signature	Accept Date	
	Department	
	Person in charge	

KYOCERA Crystal Device Corporation

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Design Department	Quality	Approved by	Checked by	logued by
YKYOCERA Crystal Device Corporation	Assurance	Approved by	Checked by	Issued by
Oscillator Division	<i>2 . 4</i>	22 17	ł	4.0
	Y. Okuyama	N. Takeno	T.Saito	H.Ishikawa

Revision History

Rev.No.	Description of revise	Date	Approved	by Checked by	Issued by
00	First edition	Dec.15,207	14 <i>N.</i> Taken	vo T.Saito	H.Ishikawa
КҮС	CERA Crystal Device Corporat	ion D	rawing No	ТКҮ1W-Н1-1	4042-00 2/8

1. Application

This specification delivers Digi-Key SAW Oscillator, KC7050T212.500L3AEYF applies to 212.500 MHz

2. Function

2-1. Absolute Maximum Rating

Item	Symbol	Rating	Unit
Power Supply Voltage	V _{DD}	-0.5 to +5.0	V
Input Voltage	V _{IN}	-0.5 to V _{CC} +0.5	V
Storage Temperature Range	T _{STG}	-55 to +125	°C

Note: If KC7050T is used beyond absolute maximum ratings, it may cause internal destruction. KC7050T should be used under the recommended operating conditions. KC7050T reliability may be damaged if those conditions are exceeded.

2-2. Recommended Operating Condition

ltem	Symbol	Min	Тур	Max	Unit	Remarks
Power Supply Voltage	V _{CC}	3.14	3.3	3.46	V	
Input Voltage	V _{IN}	0		V _{CC}	V	
Operating Temperature Range	T _{OPR}	0	+25	+85	°C	

2-3. Electrical Characteristic Specifications

Item	Symbol	Min	Тур	Мах	Unit	Remarks
Frequency Range	Fout		212.500		MHz	
Frequency Stability	F _{SBY}	-100		+100	ppm	*Over all conditions: Initial tolerance, operating temperature range, rated power supply voltage change load change, aging (5year , 0~+70°C), shock and vibration
Current Consumption	I _{CC}			70	mA	
Standby Current	I _{ST}			30	μΑ	
Duty ratio (Symmetry)	SYM	45	50	55	%	100ohm, @ 50% Vopp
Rise Time (20% to 80% Output Level)	Tr		0.4	0.6	nS	100ohm
Fall Time (20% to 80% Output Level)	Tf		0.4	0.6		
Output Voltage -"L"	V _{OL}	0.9	1.1		v	DC characteristic.
Output Voltage -"H"	V _{OH}		1.43	1.6	v	
Differential Output Voltage	V _{OD}	247	330	454	mV	DC characteristic.
Differential Output Voltage Error	$\mathrm{dV}_{\mathrm{OD}}$			50	ni v	dV _{OD} = V _{OD1} - V _{OD2}
Offset Voltage	V _{OS}	1.125	1.25	1.375	V	
Offset Voltage Error	dV _{OS}			50	mV	dV _{OS} = V _{OS1} - V _{OS2}
Output Load			100	-	ohm	LVDS Output
Input Voltage -"L"	VIL			30% V _{CC}	v	OE termination
Input Voltage -"H"	VIH	70% V _{CC}			-	
Output Disable Time				200	nS	
Output Enable Time				300	μS	
Start up time	ST			10	mS	@Minimum operating voltage to be Osec
Deterministic Jitter*	DJ		0.2	2		DJ pk-pk
1sigma Jitter*	1sigma		2	4	pS	
Peak to Peak Jitter*	Pk-Pk		20	30		
Phase Jitter	Jphase			1		BW: 12kHz to 20MHz

Note: All Electrical characteristics define Maximum Loaded and operating temperature range.

*The Time Interval Analyzer "Wavecrest DTS-2079" with VISI 6.3.1 shall measure jitter.

(Load=50ohm, @ 50% output swing)

Table 1

KYOCERA Crystal Device Corporation	Drawing No	TKY1W-H1-14042-00 3/8
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	Conditions	Criteria of Acceptance
5-1. Solderability	Soaking:	Dipped potion:
- ,	+245±5°C, 5.0±0.5sec	Minimum 95% coverage
	Reflow Soldering:	
5-2. Soldering Heat	Peak+ 260°C max, 10sec, Twice max Soldering iron:	Without looseness or crack etc
Resistance	+380±5°C, 3+1/-0sec,	Without looseness of clack etc
	Twice as one time for four Pads	
	10Cycles:	
5-3. Temperature Cycle	-55°C to +125°C (30minuts each)/cycle	
5-4. Mechanical	5 times	
Shock (Pulse)	14750m/sec ² (1500G), Duration of pulse 0.5mse	
· · · · ·	(MIL-STD-883D-2002.3 Condition I	3)
	4 times each axis X, Y, Z: 20 to 2000Hz and 2000Hz to 20Hz/cycle	Clause 5-10 shall be satisfied.
5-5. Vibration	Peak acceleration 196m/sec ² (20G)	Clause 5-10 shall be satisfied.
	(MIL-STD-883D-2007.2 Condition	A)
	1000 hours:	<u> </u>
5-6. High Temperature	Temperature:+ 85+5/-3°C	
	1000 hours:	
5-7. Low Temperature	Temperature: -40+5/-3°C	
	10 cycles:	
5-8. Humidity Cycle	Based on 1004 specifications	Clause 5-1 shall be satisfied.
	(MIL-STD-883D-1004.)	7)
5-9. Hermeticity 1 (Gross leak)	Soaking: +110±5°C, 5minutes	No bubbles appeared
5-10. Hermeticity 2	Measured by Helium Detector Device	
(Fine leak)	(MIL-STD-883D-1014.10 Condition A	5x10 ⁻⁹ Pa m ³ /sec max
	all be subjected to standard atmospheric conditions	,
Recommended La	Table2 nd pattern and soldering Guide	
2.54	2.54	
	300 Peak 260 °	C max
	250	255±5 ℃
		255±5 °C 230 °C
		255±5 °C 230 °C
		255±5 °C 230 °C
цо <u>,</u>		255±5 °C 230 °C
	250 250 200 150 to 18 150 150 150 to 18 150 150 150 150 150 150 150 150	255±5 °C 230 °C
	250 250 200 150 to 18 250 200 150 to 18 150 50 90 to 120	255±5 °C 230 °C
	250 250 200 150 to 18 150 150 150 to 18 150 150 150 150 150 150 150 150	255±5 °C 230 °C 0 °C 0 sec 30 to 40sec
Note:	250 250 200 150 to 18 250 200 150 to 18 150 50 90 to 120	255±5 °C 230 °C
Note: Since KC7050T series has in	Unit; (mm)	255±5 °C 230 °C 0 °C 0 sec 30 to 40sec Time (sec)
Note: Since KC7050T series has in	Unit; (mm) high frequency type capacitor Available Beflow time	255±5 °C 230 °C 0 °C 0 sec 30 to 40sec Time (sec)
Note: Since KC7050T series has in V _{cc} and GND, Please mount 0.01µF and 10µF to the near Fig.5 Lar	Unit; (mm) ho Bypass Capacitor between thigh frequency type capacitor rest position of oscillator.	255±5 °C 230 °C 0 °C 0 sec 30 to 40sec Time (sec)
Note: Since KC7050T series has in V _{cc} and GND, Please mount 0.01µF and 10µF to the near Fig.5 Lar Reflow Condition>	Unit; (mm) ho Bypass Capacitor between thigh frequency type capacitor rest position of oscillator. hd pattern Fig.6 Reflow p	255±5 °C 230 °C 230 °C 30 to 40sec Time (sec) es: Maximum twice
Note: Since KC7050T series has in V _{cc} and GND, Please mount 0.01µF and 10µF to the near Fig.5 Lar	Unit; (mm) ho Bypass Capacitor between thigh frequency type capacitor rest position of oscillator. hd pattern B3°C	255±5 °C 230 °C 230 °C 30 to 40sec Time (sec) es: Maximum twice

KYOCERA Crystal Device Corporation

Drawing No

TKY1W-H1-14042-00 6/8

7. Taping Specifications

7-1. Taping Quantities:

- The tape of one reel shall pack with maximum 1,000 pcs.
- KC7050T shall be contained continuously in pocket.



7-2. Leader and Blank Pocket

- Package shall consist of leader, blank pocket and loaded pocket as follows. "Fig.9"
- The power peeling top tape from carrier one shall be 0.1N {10gf} to 0.7N {70gf}. "Fig.10"





KYOCERA Crystal Device Corporation Drawi